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SCLS467E – FEBRUARY 2003 – REVISED DECEMBER 2012

# DUAL RETRIGGERABLE MONOSTABLE MULTIVIBRATOR WITH SCHMITT-TRIGGER INPUTS

Check for Samples: SN74LV123A-Q1

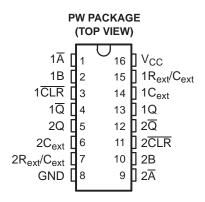
### FEATURES

- Qualified for Automotive Applications
- Typical V<sub>OLP</sub> (Output Ground Bounce)
  <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)
  >2.3 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Supports Mixed-Mode Voltage Operation on All Ports
- Schmitt-Trigger Circuitry on A, B, and CLR Inputs for Slow Input Transition Rates
- Edge Triggered From Active-High or Active-Low Gated Logic Inputs
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Retriggerable for Very Long Output Pulses, up to 100% Duty Cycle
- Overriding Clear Terminates Output Pulse
- Glitch-Free Power-Up Reset on Outputs

## DESCRIPTION/ORDERING INFORMATION

• ESD Protection Exceeds JESD 22

- 2000-V Human-Body Model (A114-A)
- 200-V Machine Model (A115-A)
- 1000-V Charged-Device Model (C101)



The SN74LV123A is a dual retriggerable monostable multivibrator designed for 2-V to 5.5-V V<sub>CC</sub> operation.

This edge-triggered multivibrator features output pulse-duration control by three methods. In the first method, the  $\overline{A}$  input is low, and the B input goes high. In the second method, the B input is high, and the  $\overline{A}$  input goes low. In the third method, the A input is low, the B input is high, and the clear (CLR) input goes high.

The output pulse duration is programmable by selecting external resistance and capacitance values. The external timing capacitor must be connected between  $C_{ext}$  and  $R_{ext}/C_{ext}$  (positive) and an external resistor connected between  $R_{ext}/C_{ext}$  and  $V_{CC}$ . To obtain variable pulse durations, connect an external variable resistance between  $R_{ext}/C_{ext}$  and  $V_{CC}$ . The output pulse duration also can be reduced by taking CLR low.

Pulse triggering occurs at a particular voltage level and is not directly related to the transition time of the input pulse. The A, B, and CLR inputs have Schmitt triggers with sufficient hysteresis to handle slow input transition rates with jitter-free triggering at the outputs.

Once triggered, the basic pulse duration can be extended by retriggering the gated low-level-active ( $\overline{A}$ ) or high-level-active (B) input. Pulse duration can be reduced by taking CLR low. The input/output timing diagram illustrates pulse control by retriggering the inputs and early clearing.

During power up, Q outputs are in the low state, and  $\overline{Q}$  outputs are in the high state. The outputs are glitch free, without applying a reset pulse.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

# SN74LV123A-Q1

#### SCLS467E - FEBRUARY 2003 - REVISED DECEMBER 2012

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#### **ORDERING INFORMATION**<sup>(1)</sup>

T <sub>A</sub>	PACKAGE <sup>(2)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING			
-40°C to 105°C	TSSOP – PW	Tape and reel	SN74LV123ATPWRQ1	LV123AQ			

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

**Table 1. FUNCTION TABLE** 

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

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#### (EACH MULTIVIBRATOR) INPUTS OUTPUTS CLR Ā в Q Q Х Х н L L L<sup>(1)</sup> H<sup>(1)</sup> Х н Х L<sup>(1)</sup> H<sup>(1)</sup> Х Х L Л ப н L ↑ Н н Л ப 1

(1) These outputs are based on the assumption that the indicated steady-state conditions at the A and B inputs have been set up long enough to complete any pulse started before the setup.

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#### Figure 1. LOGIC DIAGRAM, EACH MULTIVIBRATOR (POSITIVE LOGIC)

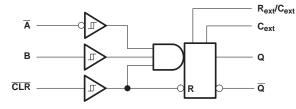
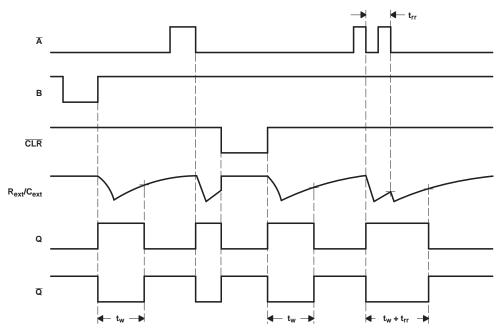


Figure 2. INPUT/OUTPUT TIMING DIAGRAM



EXAS

NSTRUMENTS

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#### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	V
VI	Input voltage range <sup>(2)</sup>		-0.5	7	V
Vo	Voltage range applied to any output in	the high-impedance or power-off state <sup>(2)</sup>	-0.5	7	V
Vo	Output voltage range in the high or low	v state <sup>(2)</sup> (3)	-0.5	V <sub>CC</sub> + 0.5	V
Vo	Dutput voltage range in power-off state <sup>(2)</sup>		-0.5	7	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-20	mA
I <sub>OK</sub>	Output clamp current	V <sub>0</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current	$V_{O} = 0$ to $V_{CC}$		±25	mA
	Continuous current through V <sub>CC</sub> or GND			±50	mA
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>			113	°C/W
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating" conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed. (2)

The value is limited to 5.5 V maximum. (3)

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

#### Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2	5.5	V
		$V_{CC} = 2 V$	1.5		
		$V_{CC}$ = 2.3 V to 2.7 V	V <sub>CC</sub> × 0.7		V
V <sub>IH</sub>	High-level input voltage	$V_{CC} = 3 V$ to 3.6 V	V <sub>CC</sub> × 0.7		v
		$V_{CC}$ = 4.5 V to 5.5 V	$V_{CC} \times 0.7$		
		$V_{CC} = 2 V$		0.5	
V	Low-level input voltage	$V_{CC}$ = 2.3 V to 2.7 V		$V_{CC} \times 0.3$	V
V <sub>IL</sub>	Low-level input voltage	$V_{CC} = 3 V$ to 3.6 V		$V_{CC} \times 0.3$	v
		$V_{CC}$ = 4.5 V to 5.5 V		$V_{CC} \times 0.3$	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		$V_{CC} = 2 V$		-50	μA
	High-level output current	$V_{CC}$ = 2.3 V to 2.7 V		-2	
I <sub>OH</sub>		$V_{CC} = 3 V \text{ to } 3.6 V$		-6	mA
		$V_{CC}$ = 4.5 V to 5.5 V		-12	
		$V_{CC} = 2 V$		50	μA
	Low-level output current	$V_{CC}$ = 2.3 V to 2.7 V		2	
I <sub>OL</sub>	Low-level output current	$V_{CC} = 3 V$ to 3.6 V		6	mA
		$V_{CC}$ = 4.5 V to 5.5 V		12	
Р	External timing registeres	$V_{CC} = 2 V$	5		kΩ
R <sub>ext</sub>	External timing resistance	$V_{CC} \ge 3 V$	1		K12
C <sub>ext</sub>	External timing capacitance		No restriction		pF
$\Delta t / \Delta V_{CC}$	Power-up ramp rate		1		ms/V
T <sub>A</sub>	Operating free-air temperature		-40	105	°C

All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, (1) Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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#### THERMAL INFORMATION

		SN74LV123ATPWRQ1	
	THERMAL METRIC <sup>(1)</sup>	TSSOP – PW	UNITS
		16 PINS	
$\theta_{JA}$	Junction-to-ambient thermal resistance <sup>(2)</sup>	111.2	
θ <sub>JCtop</sub>	Junction-to-case (top) thermal resistance <sup>(3)</sup>	46.1	
θ <sub>JB</sub>	Junction-to-board thermal resistance <sup>(4)</sup>	56.3	°C/W
τιΨ	Junction-to-top characterization parameter <sup>(5)</sup>	5.6	-0.100
Ψ <sub>JB</sub>	Junction-to-board characterization parameter <sup>(6)</sup>	55.7	
$\theta_{JCbot}$	Junction-to-case (bottom) thermal resistance <sup>(7)</sup>	n/a	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

(2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.

(3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDECstandard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

(4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.

(5) The junction-to-top characterization parameter,  $\psi_{JT}$ , estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining  $\theta_{JA}$ , using a procedure described in JESD51-2a (sections 6 and 7).

(6) The junction-to-board characterization parameter,  $\psi_{JB}$ , estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining  $\theta_{JA}$ , using a procedure described in JESD51-2a (sections 6 and 7).

(7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP	MAX	UNIT
		I <sub>OH</sub> = -50 μA	2 V to 5.5 V	V <sub>CC</sub> – 0.1			
V		$I_{OH} = -2 \text{ mA}$	2.3 V	2			V
V <sub>OH</sub>		$I_{OH} = -6 \text{ mA}$	3 V	2.48			V
		$I_{OH} = -12 \text{ mA}$	4.5 V	3.8			
		I <sub>OL</sub> = 50 μA	2 V to 5.5 V			0.1	
V		$I_{OL} = 2 \text{ mA}$	2.3 V			0.4	
V <sub>OL</sub>		I <sub>OL</sub> = 6 mA 3 V				0.44	V
		I <sub>OL</sub> = 12 mA	4.5 V			0.55	
	R <sub>ext</sub> /C <sub>ext</sub> <sup>(1)</sup>	$V_{I} = 5.5 \text{ V or GND}$	5.5 V			±2.5	
lj –			0 V			±1	μA
	$\overline{A}$ , B, and $\overline{CLR}$	$V_{I} = 5.5 V \text{ or GND}$	0 to 5.5 V		±1		
I <sub>CC</sub>	Quiescent	$V_{I} = V_{CC} \text{ or } GND,  I_{O} = 0$	5.5 V			20	μA
			3 V			280	
I <sub>CC</sub>	Active state (per circuit)	$V_I = V_{CC}$ or GND, $R_{ext}/C_{ext} = 0.5 V_{CC}$	4.5 V			650	μA
	(per circuit)		5.5 V			975	
I <sub>off</sub>		$V_1$ or $V_0 = 0$ to 5.5 V	0 V			5	μA
0			3.3 V		1.9		
Ci		$V_{I} = V_{CC}$ or GND	5 V		1.9		pF

(1) This test is performed with the terminal in the off-state condition.



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#### **Timing Requirements**

over recommended operating free-air temperature range,  $V_{CC}$  = 3.3 V ± 0.3 V (unless otherwise noted) (see Figure 3)

	PARAMETER		TEST CO	TEST CONDITIONS		λ = 25°C	MIN	МАХ	UNIT
			TEST CONDITIONS		MIN	TYP MAX	IVIIIN	WAA	UNIT
+	Pulse duration	CLR			5		5		50
w	Fuise duration	A or B trigger			5		5		ns
	Dulas retrigger time		D 110	$C_{ext} = 100 \text{ pF}$	(1)	76	(1)		ns
τ <sub>rr</sub>	t <sub>rr</sub> Pulse retrigger time		$R_{ext} = 1 k\Omega$	$C_{ext} = 0.01 \ \mu F$	(1)	1.8	(1)		μs

(1) See retriggering data in the application information section

#### **Timing Requirements**

over recommended operating free-air temperature range,  $V_{CC}$  = 5 V ± 0.5 V (unless otherwise noted) (see Figure 3)

	PARAMETER		TEST CONDITIONS		Τ,	λ = 25°C	MIN	МАХ	UNIT
					MIN	TYP MAX	IVIIIN	WAA	UNIT
+	Pulse duration	CLR			5		5		20
۱w	Fuise duration	A or B trigger			5		5		ns
	Dulas notrianan tina			C <sub>ext</sub> = 100 pF	(1)	59	(1)		ns
τ <sub>rr</sub>	t <sub>rr</sub> Pulse retrigger time		$R_{ext} = 1 k\Omega$	$C_{ext} = 0.01 \ \mu F$	(1)	1.5	(1)		μs

(1) See retriggering data in the application information section

#### **Switching Characteristics**

over recommended operating free-air temperature range,  $V_{CC}$  = 3.3 V ± 0.3 V (unless otherwise noted) (see Figure 3)

PARAMETER	FROM	то	TEST	Τ <sub>4</sub>	∖ = 25°C		MINI	MAY	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CONDITIONS	MIN	TYP	MAX	MIN	MAX	UNIT
	Ā or B	Q or Q			11.8	24.1	1	27.5	
t <sub>pd</sub>	CLR	Q or $\overline{Q}$	$C_L = 50 \text{ pF}$		10.5	19.3	1	22	ns
	CLR trigger	Q or $\overline{Q}$			12.3	25.9	1	29.5	
		Q or Q	$\begin{array}{l} C_{L} = 50 \text{ pF} \\ C_{ext} = 28 \text{ pF} \\ R_{ext} = 2 \text{ k}\Omega \end{array}$		182	240		300	ns
t <sub>w</sub> (1)			$\begin{array}{l} C_L = 50 \text{ pF} \\ C_{ext} = 0.01  \mu\text{F} \\ R_{ext} = 10  k\Omega \end{array}$	90	100	110	90	110	μs
			$\begin{array}{l} C_{L}=50 \text{ pF} \\ C_{ext}=0.1  \mu\text{F} \\ R_{ext}=10  k\Omega \end{array}$	0.9	1	1.1	0.9	1.1	ms
$\Delta t_w$ <sup>(2)</sup>			$C_L = 50 \text{ pF}$		±1				%

(1)  $t_w = Duration of pulse at Q and \overline{Q} outputs$ (2)  $\Delta t_w = Output pulse-duration variation (Q and \overline{Q}) between circuits in same package$ 

### **Switching Characteristics**

over recommended operating free-air temperature range,  $V_{CC} = 5 V \pm 0.5 V$  (unless otherwise noted) (see Figure 3)

PARAMETER	FROM	FROM TO		T <sub>A</sub> = 25°C			MIN	МАХ	UNIT
FARAMETER	(INPUT)	(OUTPUT)	CONDITIONS	MIN	TYP	MAX	IVIIIN	WAA	UNIT
	Ā or B	Q or $\overline{Q}$	C <sub>L</sub> = 50 pF		8.3	14	1	16	
t <sub>pd</sub>	CLR	Q or $\overline{Q}$			7.4	11.4	1	13	ns
	CLR trigger	Q or $\overline{Q}$			8.7	14.9	1	17	

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#### **Switching Characteristics (continued)**

over recommended operating free-air temperature range,  $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$  (unless otherwise noted) (see Figure 3)

DADAMETED	FROM	то	TEST	T <sub>A</sub> = 25°C			MIN	MAV	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CONDITIONS	MIN	TYP	MAX	WIIIN	MAX	UNII
	t <sub>w</sub> <sup>(1)</sup> Q or Q	$C_{L} = 50 \text{ pF}$ $C_{ext} = 28 \text{ pF}$ $R_{ext} = 2 \text{ k}\Omega$		167	200		240	ns	
t <sub>w</sub> <sup>(1)</sup>		Q or $\overline{Q}$	$\begin{array}{l} C_L = 50 \text{ pF} \\ C_{ext} = 0.01  \mu\text{F} \\ R_{ext} = 10  k\Omega \end{array}$	90	100	110	90	110	μs
			$\begin{array}{c} C_L = 50 \text{ pF} \\ C_{ext} = 0.1  \mu\text{F} \\ R_{ext} = 10  k\Omega \end{array}$	0.9	1	1.1	0.9	1.1	ms
$\Delta t_w$ <sup>(2)</sup>			C <sub>L</sub> = 50 pF		±1				%

(1)  $t_w =$  Duration of pulse at Q and  $\overline{Q}$  outputs

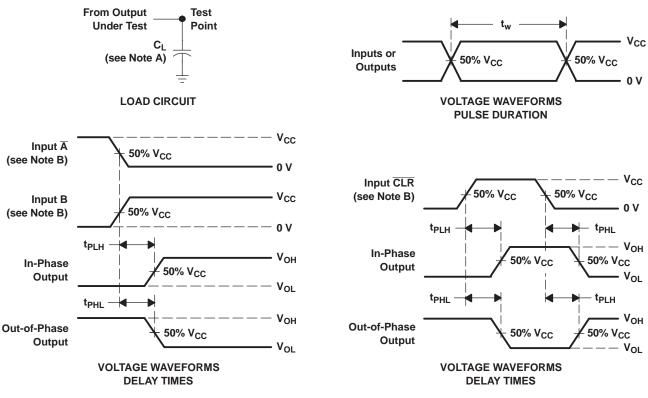
(2)  $\Delta t_w =$ Output pulse-duration variation (Q and  $\overline{Q}$ ) between circuits in same package

#### **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST C	Vcc	ТҮР	UNIT	
C <sub>pd</sub>	Device discipation accessitence	C <sub>L</sub> = 50 pF,		3.3 V	44	pF
	Power dissipation capacitance		f = 10 MHz	5 V	49	

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_L$  includes probe and jig capacitance.

B. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>r</sub> = 3 ns, t<sub>f</sub> = 3 ns.

C. The outputs are measured one at a time, with one input transition per measurement.

#### Figure 3. Load Circuit and Voltage Waveforms

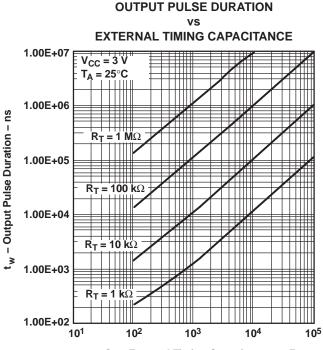
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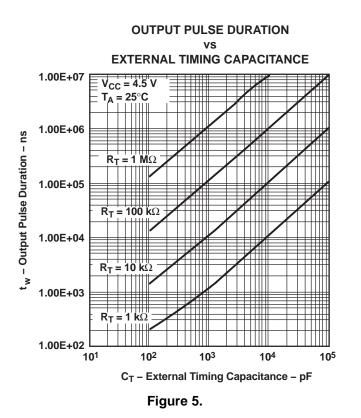
#### APPLICATION INFORMATION

Operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied.



C<sub>T</sub> – External Timing Capacitance – pF





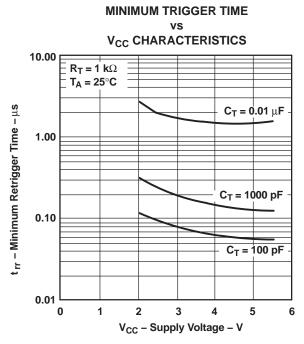
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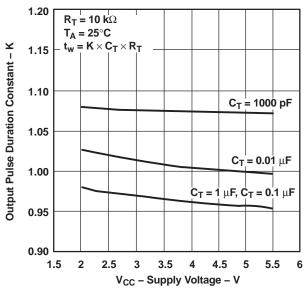
#### **APPLICATION INFORMATION**

Operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied.





#### OUTPUT PULSE-DURATION CONSTANT vs SUPPLY VOLTAGE





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#### **Caution In Use**

To prevent malfunctions due to noise, connect a high-frequency capacitor between  $V_{CC}$  and GND, and keep the wiring between the external components and  $C_{ext}$  and  $R_{ext} / C_{ext}$  terminals as short as possible.

#### Power-Down Considerations

Large values of C<sub>ext</sub> can cause problems when powering down the 'LV123A devices because of the amount of energy stored in the capacitor. When a system containing this device is powered down, the capacitor can discharge from V<sub>CC</sub> through the protection diodes at pin 2 or pin 14. Current through the input protection diodes must be limited to 30 mA; therefore, the turn-off time of the V<sub>CC</sub> power supply must not be faster than t = V<sub>CC</sub> × C<sub>ext</sub> / 30 mA. For example, if V<sub>CC</sub> = 5 V and Cext = 15 pF, the V<sub>CC</sub> supply must turn off no faster than t = (5 V) × (15 pF) / 30 mA = 2.5 ns. Usually, this is not a problem because power supplies are heavily filtered and cannot discharge at this rate. When a more rapid decrease of V<sub>CC</sub> to zero occurs, the 'LV123A devices can sustain damage. To avoid this possibility, use external clamping diodes.

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#### **REVISION HISTORY**

Cł	Changes from Revision D (April 2008) to Revision E						
•	Added thermal information table	4					
•	Added Caution section describing power-down timing.	9					

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#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Samples
	(1)		Drawing			(2)		(3)	(Requires Login)
SN74LV123ATPWRG4Q1	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LV123ATPWRQ1	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF SN74LV123A-Q1 :

• Catalog: SN74LV123A

Enhanced Product: SN74LV123A-EP

## PACKAGE OPTION ADDENDUM



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18-Dec-2012

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications

PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.  $\beta$ . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



# PW (R-PDSO-G16)

# PLASTIC SMALL OUTLINE



- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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